

Description

The AP65550 is an adaptive constant on-time mode synchronous buck converter providing high efficiency, excellent transient response and high DC output accuracy for low-voltage regulation in digital TV and monitor.

The constant-on-time control scheme handles wide input/output voltage ratios and provides low external component count. The internal proprietary circuit enables the device to adopt both low equivalent series resistance (ESR) output capacitors, such as SP-CAP or POSCAP and ultra-low ESR ceramic capacitors.

The adaptive on-time control supports seamless transition between continuous conduction mode (CCM) at higher load conditions and discontinuous conduction mode (DCM) at lighter load conditions.

DCM allows AP65550 maintain high efficiency at light load conditions. The AP65550 also features programmable soft-start, UVLO, OTP and OCP to protect the circuit.

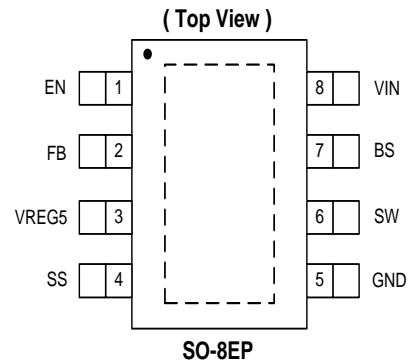
This IC is available in SO-8EP package.

Features

- Fixed Frequency Emulated Constant On-time Control
- Good Stability Independent of the Output Capacitor ESR
- Fast Load Transient Response
- Synchronous Rectification: 65mΩ Internal High-side Switch and 36mΩ Internal Low-side Switch
- Wide Input Voltage Range: 4.5V to 18V
- Output Voltage Range: 0.76V to 6V
- 5A Continuous Output Current
- 650kHz Switching Frequency
- Built-in Over Current Limit
- Built-in Thermal Shutdown Protection
- Programmable Soft-start
- Pre-biased Start-up
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Pin Assignments



Applications

- Gaming Consoles
- Flat Screen TV sets and Monitors
- Set Top Boxes
- Distributed power systems
- Home Audio
- Consumer electronics
- Network Systems
- FPGA, DSP and ASIC Supplies
- Green Electronics

Typical Applications Circuit

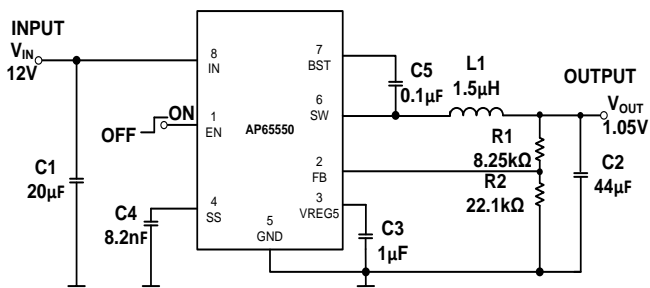
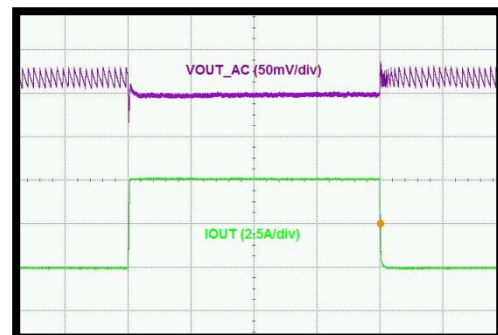


Figure 1. Typical Application Circuit



Pin Descriptions

Pin Name	Pin Number SO-8EP	Function
EN	1	Enable input. EN is a digital input that turns the regulator on or off. Drive EN high to turn on the regulator, drive it low to turn off. Pull up with 100kΩ resistor for automatic startup.
FB	2	Feedback Input. FB senses the output voltage and regulates it. Drive FB with a resistive voltage divider connected to it from the output voltage.
VREG5	3	Internal power supply output pin to connect an additional capacitor. Connect a 1μF (typical) capacitor as close as possible to the VREG5 and GND. This pin is not active when EN is low.
SS	4	Soft-start control input pin. SS controls the soft start period. Connect a capacitor from SS to GND to set the soft-start period.
GND	5	Ground pin is the main power ground for the switching circuit.
SW	6	Power Switching Output. SW is the switching node that supplies power to the output. Connect the output LC filter from SW to the output load. Note that a capacitor is required from SW to BS to power the high-side switch.
BS	7	Bootstrap pin. A bootstrap capacitor is connected between the BS pin and SW pin. The voltage across the bootstrap capacitor drives the internal high-side NMOS switch. A 0.1μF (typical) capacitor is required for proper operation
VIN	8	Supply input pin. A capacitor should be connected between the VIN pin and GND pin to keep the DC input voltage constant.
EP	—	Connect the exposed thermal pad to GND on the PCB

Functional Block Diagram

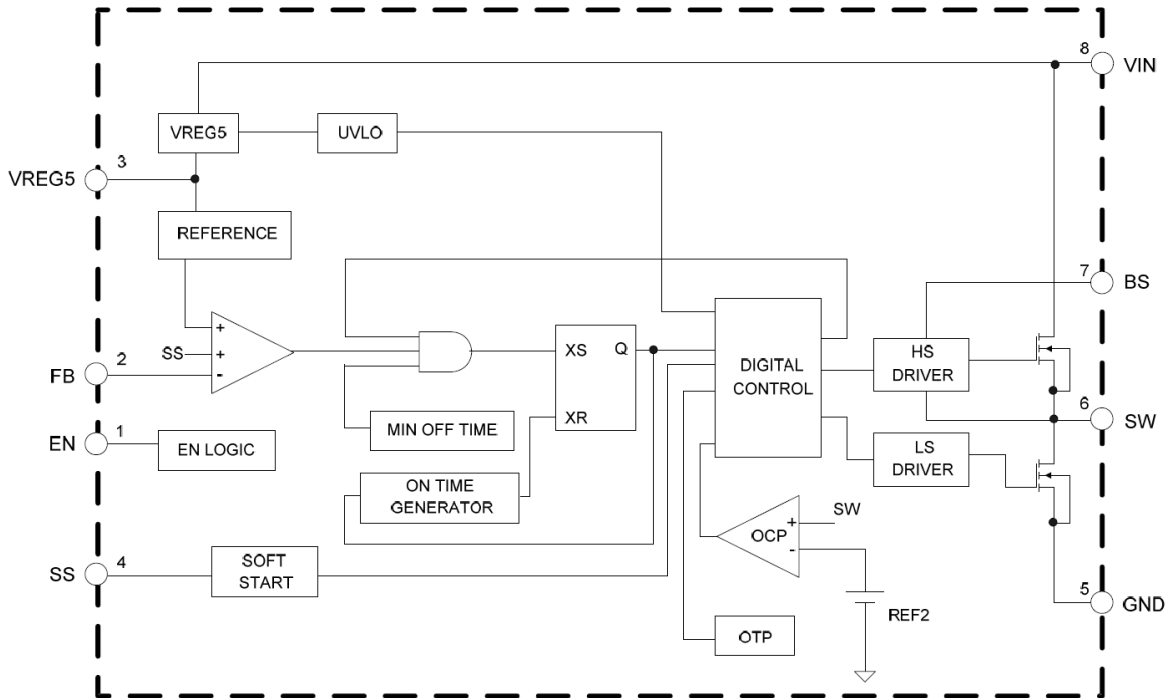


Figure 2. Functional Block Diagram

Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
V _{IN}	Supply Voltage	-0.3 to 20	V
V _{REG5}	VREG5 Pin Voltage	-0.3V to +6.0	V
V _{SW}	Switch Node Voltage	-1.0 to V _{IN} +0.3	V
V _{BS}	Bootstrap Voltage	-0.3 to V _{SW} +6.0	V
V _{FB}	Feedback Voltage	-0.3V to +6.0	V
V _{EN}	Enable/UVLO Voltage	-0.3V to +6.0	V
V _{SS}	SoftStart PIN	-0.3V to +6.0	V
V _{GND}	GND Pin Voltage	-0.3 to 0.3	V
T _{ST}	Storage Temperature	-65 to +150	°C
T _J	Junction Temperature	+160	°C
T _L	Lead Temperature	+260	°C
ESD Susceptibility (Note 5)			
HBM	Human Body Model	2	kV
MM	Machine Model	200	V

- Notes:
- Stresses greater than the 'Absolute Maximum Ratings' specified above may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability may be affected by exposure to absolute maximum rating conditions for extended periods of time.
 - Semiconductor devices are ESD sensitive and may be damaged by exposure to ESD events. Suitable ESD precautions should be taken when handling and transporting these devices.

Thermal Resistance (Note 6)

Symbol	Parameter	Rating		Unit
θ _{JA}	Junction to Ambient	SO-8EP	70	°C/W
θ _{JC}	Junction to Case	SO-8EP	30	°C/W

- Note: 6. Test condition: SO-8: Device mounted on 1"x1" FR-4 substrate PCB, 2oz copper, with minimum recommended pad layout.

Recommended Operating Conditions (Note 7) (@T_A = +25°C, unless otherwise specified.)

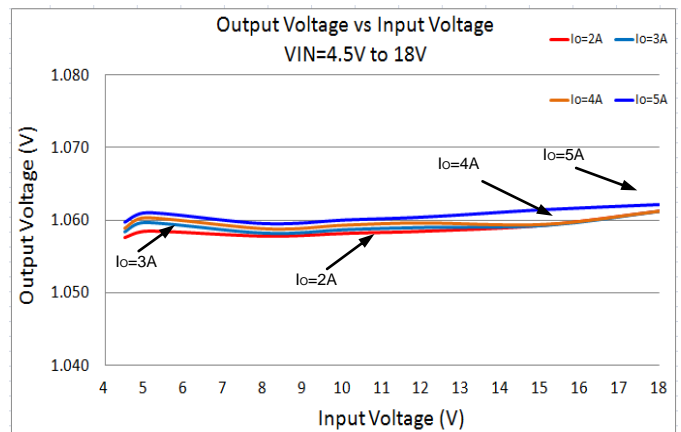
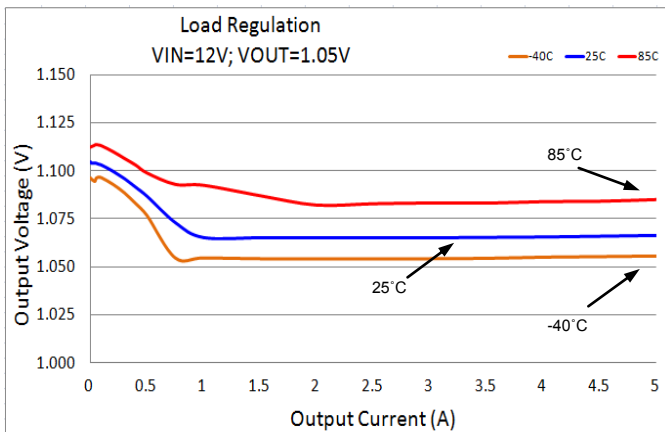
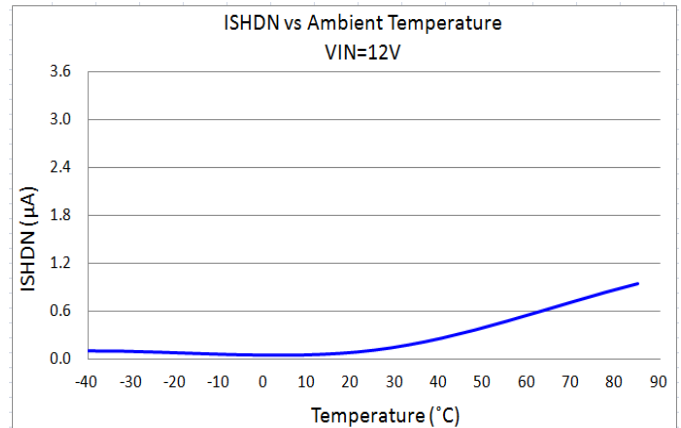
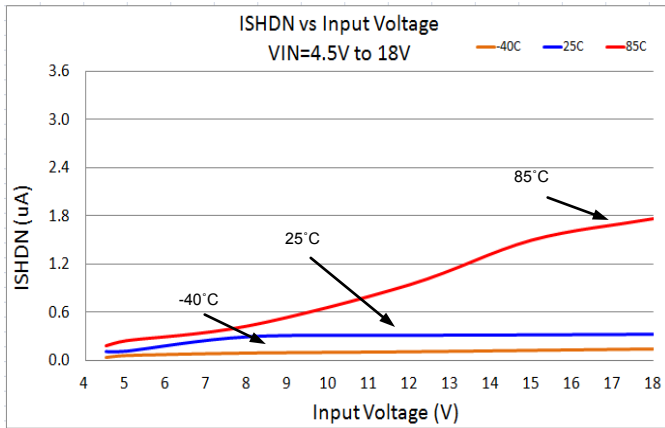
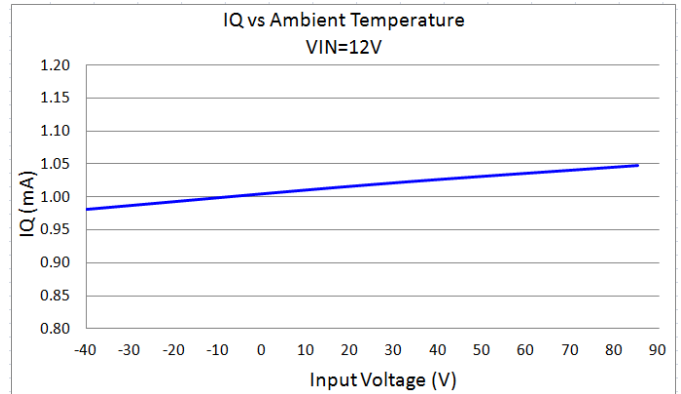
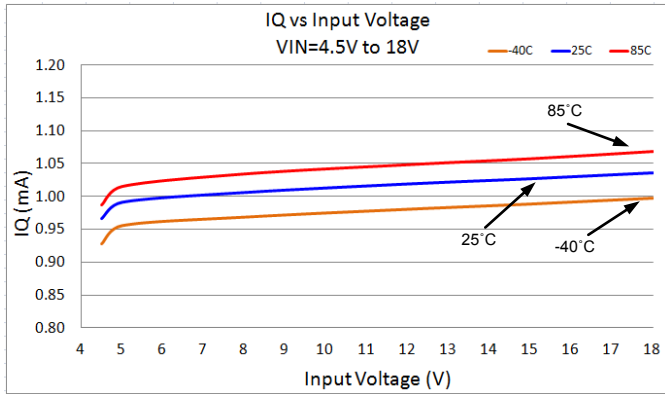
Symbol	Parameter	Min	Max	Unit
V _{IN}	Supply Voltage	4.5	18.0	V
T _J	Operating Junction Temperature Range	-40	+125	°C
T _A	Operating Ambient Temperature Range	-40	+85	°C

- Note: 7. The device function is not guaranteed outside of the recommended operating conditions.

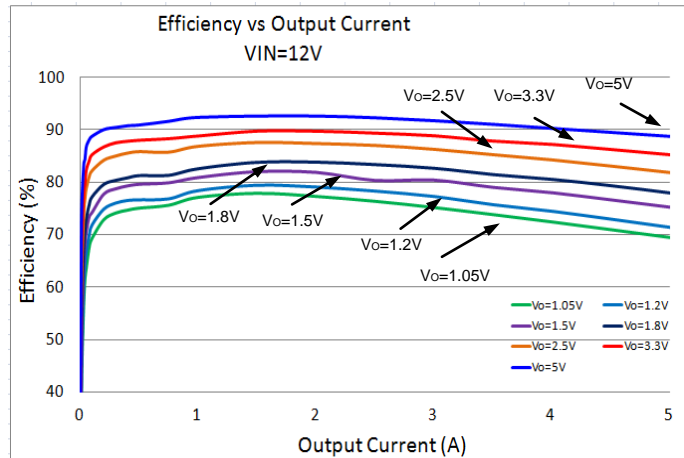
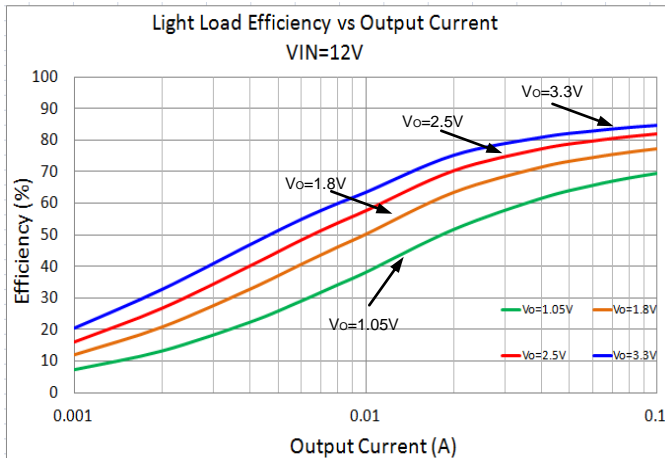
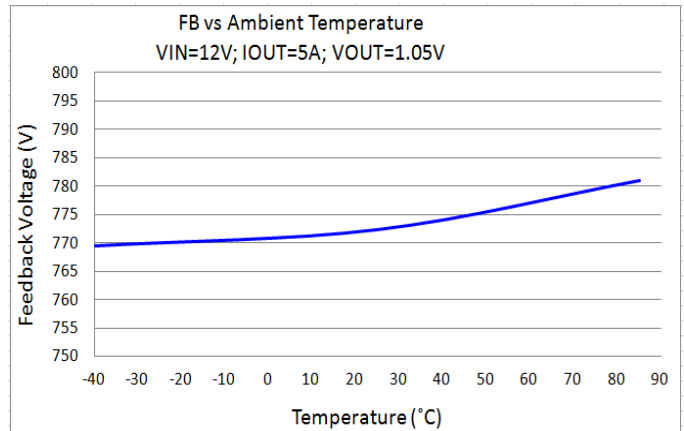
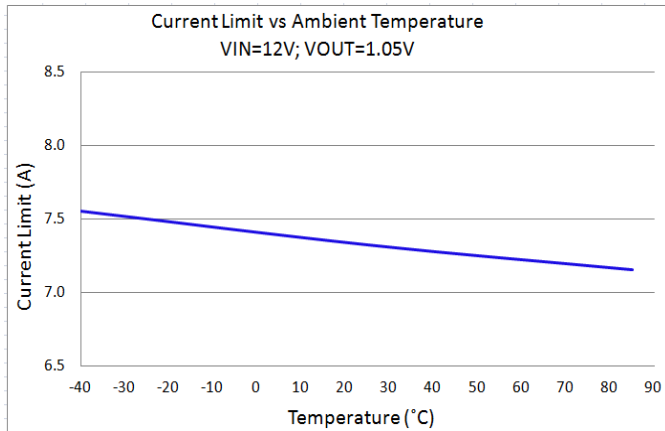
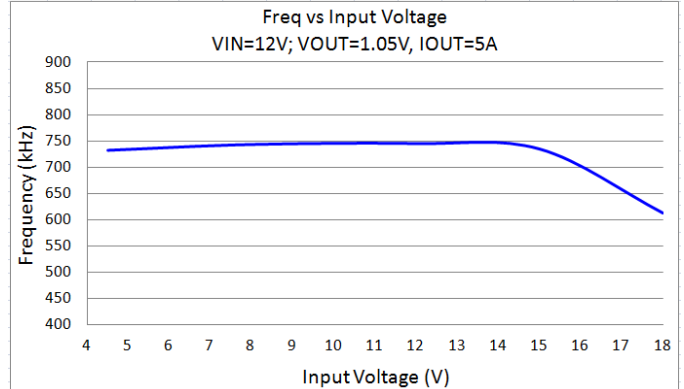
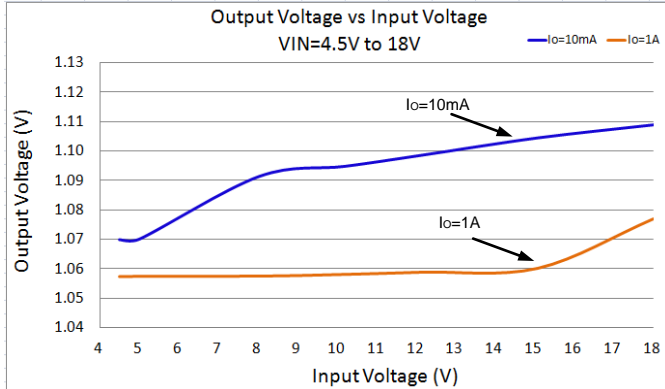
Electrical Characteristics (@T_A = +25°C, V_{IN} = 12V, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
SUPPLY VOLTAGE (VIN PIN)						
Input Voltage	V _{IN}	—	4.5	—	18	V
Quiescent Current	I _Q	V _{FB} =0.85V	—	0.9	—	mA
Shutdown Supply Current	I _{SHDN}	V _{EN} =0V	—	3.6	10	μA
UNDER VOLTAGE LOCKOUT						
UVLO Threshold	V _{UVLO}	V _{IN} Rising Test V _{REG5} Voltage	3.45	3.75	4.05	V
UVLO Hysteresis	V _{HYS}	V _{IN} Falling Test V _{REG5} Voltage	0.19	0.32	0.45	V
ENABLE (EN PIN)						
EN High-level Input Voltage	V _{ENH}	—	1.9	—	—	V
EN Low-level Input Voltage	V _{ENL}	—	—	—	0.6	V
VOLTAGE REFERENCE (FB PIN)						
Feedback Voltage	V _{FB}	V _{OUT} =1.05V	0.753	0.765	0.777	V
Feedback Bias Current	I _{FB}	V _{FB} =0.8V	-0.1	0	0.1	μA
VREG5 OUTPUT						
VREG5 Output Voltage	V _{VREG5}	6.0V < V _{IN} < 18V 0 < I _{VREG5} < 5mA	4.7	5.1	5.5	V
Source Current Capability	—	V _{IN} =6V, V _{VREG5} =4V	—	110	—	mA
Load Regulation	—	0 < I _{VREG5} < 5mA	—	—	60	mV
Line Regulation	—	6.0V < V _{IN} < 18V I _{VREG5} =5mA	—	—	20	mV
MOSFET						
High-side Switch On-resistance	R _{DSONH}	—	—	0.065	—	Ω
Low-side Switch On-resistance	R _{DSONL}	—	—	0.036	—	Ω
CURRENT LIMIT						
High Level Current Limit	I _{LIM-H}	L=1.5μH	5.6	6.4	7.9	A
ON-TIME TIMER						
On Time	t _{ON}	V _{IN} =12V, V _{OUT} =1.05V	—	150	—	ns
Minimum Off Time	t _{OFF-MIN}	V _{FB} =0.7V	—	260	310	ns
THERMAL SHUTDOWN						
Thermal Shutdown	T _{TOTSD}	—	—	+160	—	°C
Thermal Shutdown Hysteresis	T _{HYS}	—	—	+30	—	°C
SOFT START (SS PIN)						
Soft-start Source Current	I _{SS-SOURCE}	V _{SS} =1V	4.2	6.0	7.8	μA
Soft-start Discharge Current	I _{SS-DISCHARGE}	V _{SS} =0.5V	0.1	0.2	—	mA

Typical Performance Characteristics (@ $T_A = +25^\circ\text{C}$, $V_{IN} = 12\text{V}$, $V_{OUT} = 3.3\text{V}$, unless otherwise specified.)

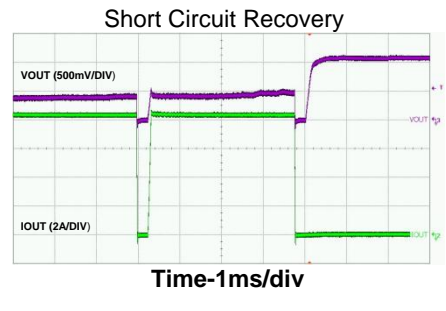
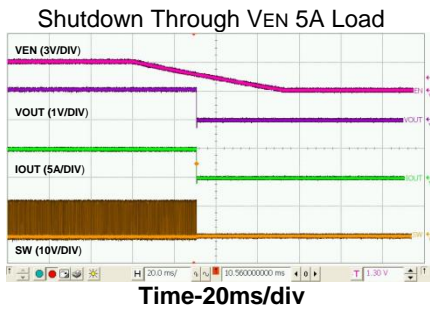
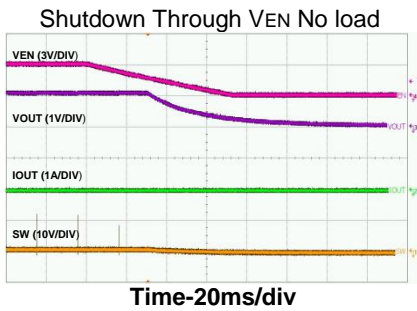
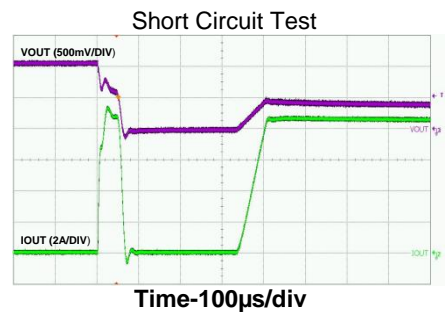
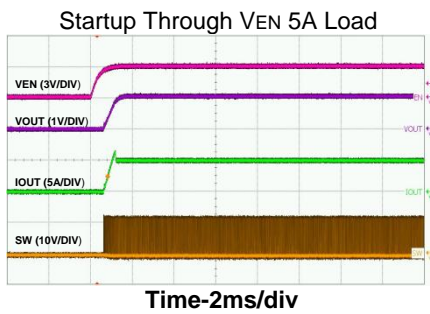
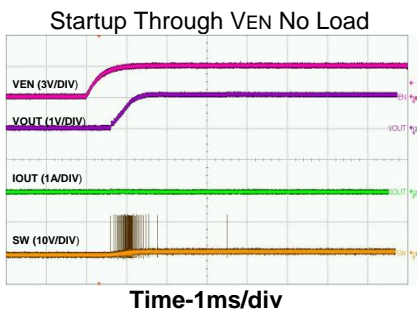
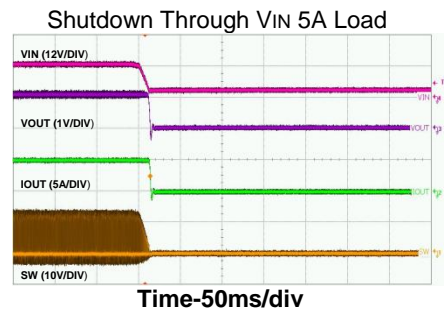
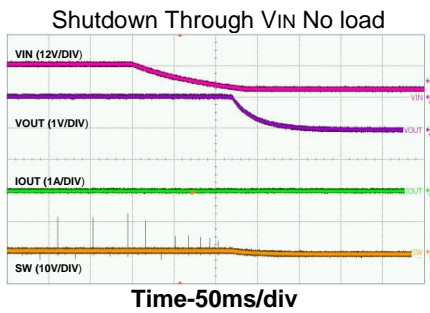
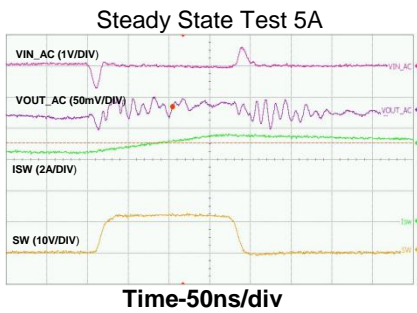
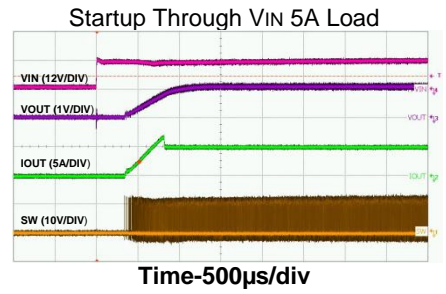
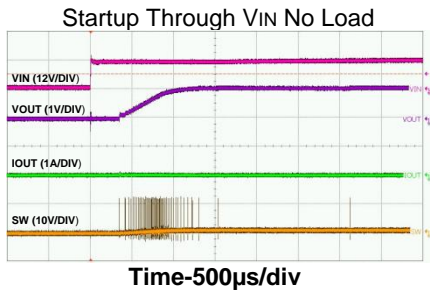
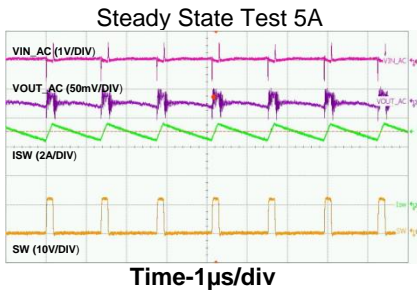


Typical Performance Characteristics (cont.) (@ $T_A = +25^\circ\text{C}$, $V_{IN} = 12\text{V}$, $V_{OUT} = 3.3\text{V}$, unless otherwise specified.)



Typical Performance Characteristics (cont.)

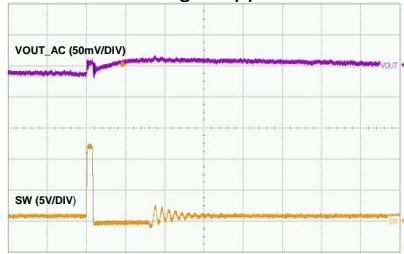
(@T_A = +25°C, V_{IN} = 12V, V_{OUT} = 1.05V, L = 1.5μH, C1 = 20μF, C2 = 44μF, unless otherwise specified.)



Typical Performance Characteristics (cont.)

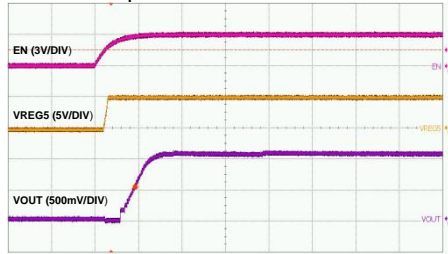
(@T_A = +25°C, V_{IN} = 12V, V_{OUT} = 1.05V, L = 1.5μH, C1 = 20μF, C2 = 44μF, unless otherwise specified.)

DCM Voltage Ripple 30mA



Time-1μs/div

Startup with VREG5 No Load



Time-1ms/div

Application Information

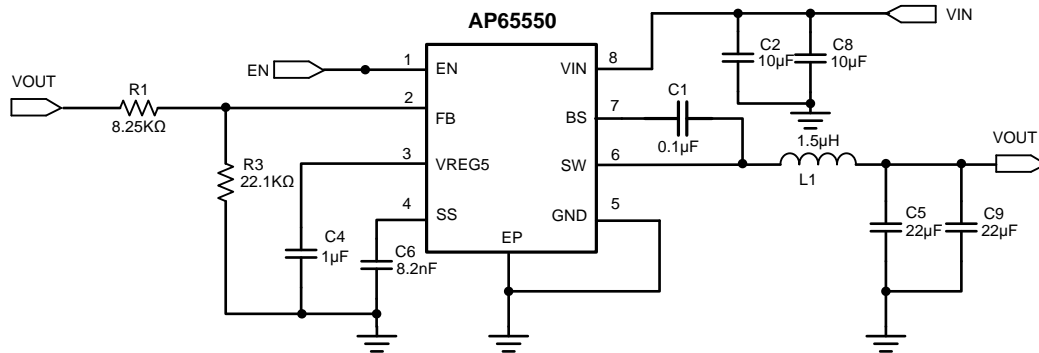


Figure 3. Typical Application of AP65550

PWM Operation and Adaptive On-time Control

The AP65550 is synchronous step-down converters with internal power MOSFETs. Adaptive constant on time (COT) control is employed to provide fast transient response and easy loop stabilization. At the beginning of each cycle, the high-side MOSFET is turned on. This MOSFET is turned off after internal one shot timer expires. This one shot is set by the converter input voltage (V_{IN}), and the output voltage (V_{OUT}) to maintain a pseudo-fixed frequency over the input voltage range, hence it is called adaptive on-time control. The output voltage variation is sensed by FB voltage. The one-shot timer is reset and the high-side MOSFET is turned on again when FB voltage falls below the 0.76V.

AP65550 uses an adaptive on-time control scheme and does not have a dedicated in board oscillator. It runs with a pseudo-constant frequency of 650kHz by using the input voltage and output voltage to set the on-time one-shot timer. The on-time is inversely proportional to the input voltage and proportional to the output voltage. It can be calculated using the following equation:

$$T_{ON} = \frac{V_{OUT}}{V_{IN} \times f}$$

V_{OUT} is the output voltage

V_{IN} is the input voltage

f is the switching frequency

After an ON-time period, the AP65550 goes into the OFF-time period. The OFF-time period length depends on VFB in most case. It will end when the FB voltage decreases and below 0.76V then the ON-time periods is triggered. If the OFF-time period is less than the minimum OFF time, the minimum OFF time will be applied, which is about 260ns typical.

Power Save Mode

The AP65550 is designed with Power Save Mode (PSM) at light load conditions for high efficiency. The AP65550 automatically reduces the switching frequency and change the T_{on} time to T_{min-on} time during a light load condition to get high efficiency and low output ripple. As the output current decreases from heavy load condition, the inductor current decreases as well, eventually comes close to zero current, which is the boundary between CCM and DCM. The low side MOSFET is turned off when the inductor current reaches zero level. The load is provided only by output capacitor, when FB voltage is lower than 0.76V, the next cycle ON cycle is beginning. The on-time is the minimum on time that benefit for decreasing V_{OUT} ripple at light load condition. When the output current increases from light to heavy load, the switching frequency increases to keep output voltage. The transition point to light load operation can be calculated using the following equation:

$$I_{LOAD} = \frac{V_{IN} - V_{OUT}}{2L} \times T_{ON}$$

T_{ON} is on-time

Enable

Above the 'EN high-level input voltage', the internal regulator is turned on and the quiescent current can be measured above this threshold. The enable (EN) input allows the user to control turning on or off the regulator. To enable the AP65550, EN must be pulled above the 'EN high-level input voltage' and to disable the AP65550, EN must be pulled below 'EN low-level input voltage'.

Application Information (cont.)

Soft-start

The soft-start time of the AP65550 is programmable by selecting different C_{SS} value. When the EN pin becomes high, the C_{SS} is charged by a 6µA current source, generating a ramp signal fed into non-inverting input of the error comparator. Reference voltage V_{REF} or the internal soft-start voltage SS whichever is smaller dominates the behavior of the non-inverting inputs of the error amplifier. Accordingly, the output voltage will follow the SS signal and ramp up smoothly to its target level. The capacitor value required for a given soft-start ramp time can be expressed as:

$$t_{SS} = \frac{C_{SS} \times V_{FB}}{I_{SS}}$$

Where C_{SS} is the required capacitor between SS pin and GND, t_{SS} is the desired soft-start time and V_{FB} is the feedback voltage.

Over Current Protection (OCP)

Figure 4 shows the over current protection (OCP) scheme of AP65550. In each switching cycle, the inductor current is sensed by monitoring the low-side MOSFET in the OFF period. When the voltage between GND pin and SW pin is smaller than the over current trip level, the OCP will be triggered and the controller keeps the OFF state. A new switching cycle will begging when the measured voltage is larger than limit voltage. The internal counter is incremented when OCP is triggered. After 16 sequential cycles, the internal OCL (Over Current Logic) threshold is set to a lower level, reducing the available output current. When a switching cycle occurs where the switch current is below the lower OCL threshold, the counter is reset and OCL limit is returned to higher value.

Because the R_{DS(ON)} of MOSFET increases with temperature, V_{Limit} has xppm/°C temperature coefficient to compensate this temperature dependency of R_{DS(ON)}.

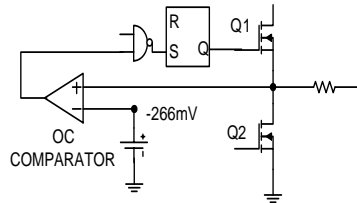


Figure 4. Over Current Protection Scheme

Under Voltage Lockout

The AP65550 provides an under voltage lockout circuit to prevent it from undefined status when startup. The UVLO circuit shuts down the device when V_{IN} drops below 3.45V. The UVLO circuit has 320mV hysteresis, which means the device starts up again when V_{REG} rise to 3.75V. (non-latch)

Thermal shutdown

If the junction temperature of the device reaches the thermal shutdown limit of 160°C, the AP65550 shuts itself off, and both HMOS and LMOS will be turned off. The output is discharge with the internal transistor. When the junction cools to the required level (130°C nominal), the device initiates soft-start as during a normal power -up cycle.

Setting the Output Voltage

The output voltage can be adjusted from 1.000 to 5V using an external resistor divider. Table 1 shows a list of resistor selection for common output voltages. Resistor R1 is selected based on a design tradeoff between efficiency and output voltage accuracy. For high values of R1 there is less current consumption in the feedback network. However the trade off is output voltage accuracy due to the bias current in the error amplifier. R1 can be determined by the following equation:

$$R_1 = R_2 \cdot \left(\frac{V_{OUT}}{0.765} - 1 \right)$$

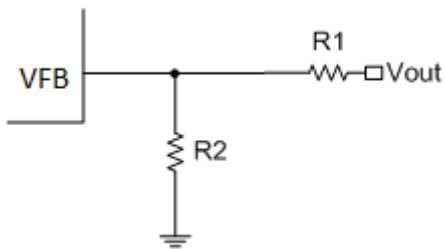


Figure 5. Feedback Divider Network

Output Voltage (V)	R1 (kΩ)	R2 (kΩ)
1	6.81	22.1
1.05	8.25	22.1
1.2	12.7	22.1
1.5	21.5	22.1
1.8	30.1	22.1
2.5	49.9	22.1
3.3	73.2	22.1
5	124	22.1

Table 1. Resistor Selection for Common Output

Application Information (cont.)

Inductor

Calculating the inductor value is a critical factor in designing a buck converter. For most designs, the following equation can be used to calculate the inductor value;

$$L = \frac{V_{OUT} \cdot (V_{IN} - V_{OUT})}{V_{IN} \cdot \Delta I_L \cdot f_{SW}}$$

Where ΔI_L is the inductor ripple current.

And f_{SW} is the buck converter switching frequency.

Choose the inductor ripple current to be 30% of the maximum load current. The maximum inductor peak current is calculated from:

$$I_{L(MAX)} = I_{LOAD} + \frac{\Delta I_L}{2}$$

Peak current determines the required saturation current rating, which influences the size of the inductor. Saturating the inductor decreases the converter efficiency while increasing the temperatures of the inductor and the internal MOSFETs. Hence choosing an inductor with appropriate saturation current rating is important.

A 1 μ H to 3.3 μ H inductor with a DC current rating of at least 25% percent higher than the maximum load current is recommended for most applications. For highest efficiency, the inductor's DC resistance should be less than 100m Ω . Use a larger inductance for improved efficiency under light load conditions.

The phase boost can be achieved by adding a additional feed forward capacitor (C4) in parallel with R1.

Output Voltage (V)	C10(pF)	L1(μ H)	C5+C9(μ F)
1	—	1.0-1.5	22-68
1.05	—	1.0-1.5	22-68
1.2	—	1.0-1.5	22-68
1.5	—	1.5	22-68
1.8	5-22	1.5	22-68
2.5	5-22	2.2	22-68
3.3	5-22	2.2	22-68
5	5-22	3.3	22-68

Table 2. Recommended Component Selection

Input Capacitor

The input capacitor reduces the surge current drawn from the input supply and the switching noise from the device. The input capacitor has to sustain the ripple current produced during the on time on the upper MOSFET. It must hence have a low ESR to minimize the losses.

The RMS current rating of the input capacitor is a critical parameter that must be higher than the RMS input current. As a rule of thumb, select an input capacitor which has RMs rating that is greater than half of the maximum load current.

Due to large di/dt through the input capacitors, electrolytic or ceramics should be used. If a tantalum must be used, it must be surge protected. Otherwise, capacitor failure could occur. For most applications, greater than 10 μ F ceramic capacitor is sufficient.

Output Capacitor

The output capacitor keeps the output voltage ripple small, ensures feedback loop stability and reduces the overshoot of the output voltage. The output capacitor is a basic component for the fast response of the power supply. In fact, during load transient, for the first few microseconds it supplies the current to the load. The converter recognizes the load transient and sets the duty cycle to maximum, but the current slope is limited by the inductor value.

Application Information (cont.)

Output Capacitor (cont.)

Maximum capacitance required can be calculated from the following equation:

ESR of the output capacitor dominates the output voltage ripple. The amount of ripple can be calculated from the equation below:

$$V_{out_capacitor} = \Delta I_{inductor} * ESR$$

An output capacitor with ample capacitance and low ESR is the best option. For most applications, a 22µF to 68µF ceramic capacitor will be sufficient.

$$C_o = \frac{L(I_{out} + \frac{\Delta I_{inductor}}{2})^2}{(\Delta V + V_{out})^2 - V_{out}^2}$$

Where ΔV is the maximum output voltage overshoot.

Bootstrap Capacitor

To ensure the proper operation, a ceramic capacitor must be connected between the VBST and SW pin. A 0.1µF ceramic capacitor is sufficient.

VREG5 Capacitor

To ensure the proper operation, a ceramic capacitor must be connected between the VREG5 and GND pin. A 1µF ceramic capacitor is sufficient.

PC Board Layout

1. The AP65550 works at 5A load current, heat dissipation is a major concern in layout the PCB. A 2oz Copper in both top and bottom layer is recommended.
2. Provide sufficient vias in the thermal exposed pad for heat dissipate to the bottom layer.
3. Provide sufficient vias in the Output capacitor GND side to dissipate heat to the bottom layer.
4. Make the bottom layer under the device as GND layer for heat dissipation. The GND layer should be as large as possible to provide better thermal effect.
5. Make the Vin capacitors as close to the device as possible.
6. Make the VREG5 capacitor as close to the device as possible.
7. The thermal pad of the device should be soldered directly to the PCB exposed copper plane to work as a heatsink. The thermal vias in the exposed copper plane increase the heat transfer to the bottom layer.

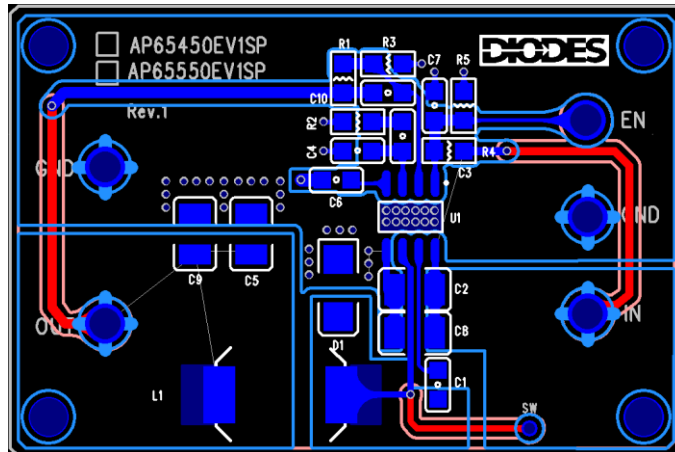
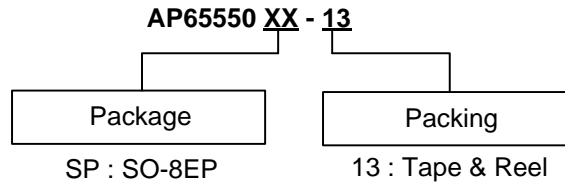


Figure 6. PC Board Layout

Ordering Information

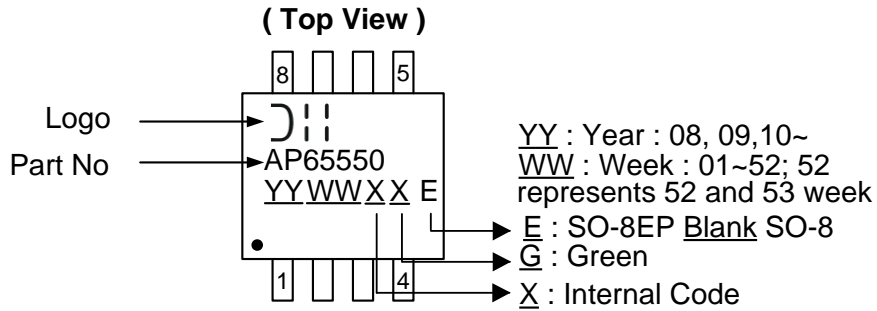


Part Number	Package Code	Part Marking	Identification Code	Tape and Reel	
				Quantity	Part Number Suffix
AP65550SP-13	SP	SO-8EP	—	2500	-13

Note: 8. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>

Marking Information

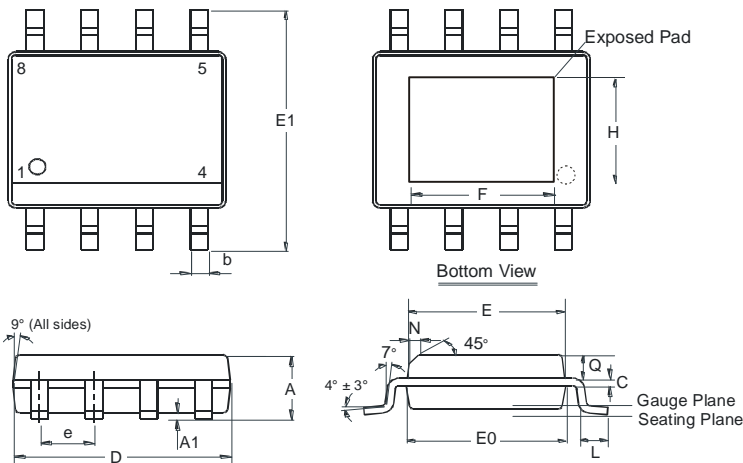
(1) SO-8EP



Package Outline Dimensions (All dimensions in mm.)

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.

(1) SO-8EP

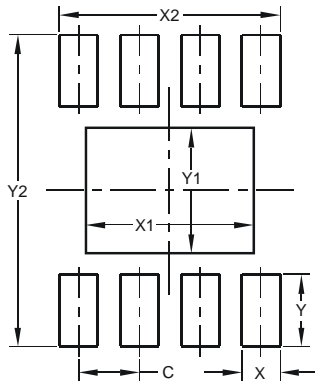


SO-8EP (SOP-8L-EP)			
Dim	Min	Max	Typ
A	1.40	1.50	1.45
A1	0.00	0.13	-
b	0.30	0.50	0.40
C	0.15	0.25	0.20
D	4.85	4.95	4.90
E	3.80	3.90	3.85
E0	3.85	3.95	3.90
E1	5.90	6.10	6.00
e	-	-	1.27
F	2.75	3.35	3.05
H	2.11	2.71	2.41
L	0.62	0.82	0.72
N	-	-	0.35
Q	0.60	0.70	0.65
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.

(1) SO-8EP



Dimensions	Value (in mm)
C	1.270
X	0.802
X1	3.502
X2	4.612
Y	1.505
Y1	2.613
Y2	6.500

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